TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

2SK4037

470 MHz Band Amplifier Applications

(Note)The TOSHIBA products listed in this document are intended for high frequency Power Amplifier of telecommunications equipment. These TOSHIBA products are neither intended nor warranted for any other use. Do not use these TOSHIBA products listed in this document except for high frequency Power Amplifier of telecommunications equipment

• Output power: $P_0 = 35.50 dBmW (3.5 W) (min)$

• Gain: $G_p = 10.50 dB \text{ (min)}$

• Drain Efficiency: $\eta D = 60.0\%$ (typ)

Maximum Ratings (Ta = 25°C)

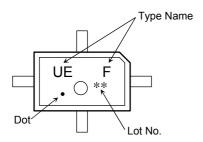
Characteristics	Symbol	Rating	Unit
Drain-source voltage	V_{DSS}	12	V
Gate-source voltage	V _{GSS} (Note 1)	3	V
Drain current	I _D	3	Α
Power dissipation	P _D (Note 2)	20	W
Channel temperature	T _{ch}	150	°C
Storage temperature range	T _{stg}	-45~150	°C

Note 1: Recommended Opelation Condition: 0~3V

Note 2: Tc = 25°C (When mounted on a 0.8 mm glass epoxy PCB)

Unit: mm Toshiba 2-5N1A

Marking



Caution: This device is sensitive to electrostatic discharge.

Please make enough tool and equipment earthed when you handle.

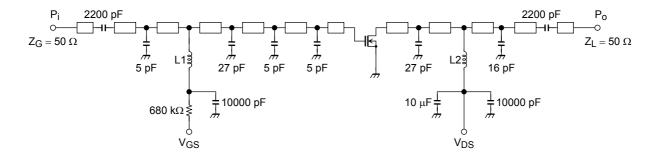
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Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Output power	Po	V _{DS} = 6.0 V, lidle = 250 mA	35.5	36.0	_	dBmW
Drain efficiency	η_{D}	(V _{GS} = adjust) f = 470 MHz, P _i = 25dBmW	55.0	60.0	_	%
Power gain	Gp	$Z_G = Z_L = 50 \Omega$	_	11.0	_	dB
Threshold voltage	V _{th}	$V_{DS} = 6.0 \text{ V}, I_{D} = 0.5 \text{ mA}$	_	1.0	1.5	٧
Drain cut-off current	I _{DSS}	V _{DS} = 12 V, V _{GS} = 0 V	_	_	10	μA
Gate-source leakage current	I _{GSS}	V _{GS} = 3V, V _{DS} = 0 V	_	_	5	μA
Load mismatch (Note 2)	_	V_{DS} = 6.0 V, f = 470 MHz, P_i = 25dBmW, P_0 = 35.5dBmW (V_{GS} = adjust) VSWR LOAD 10:1 all phase	No degradation		_	

Note 2: These characteristic values are measured using measurement tools specified by Toshiba.

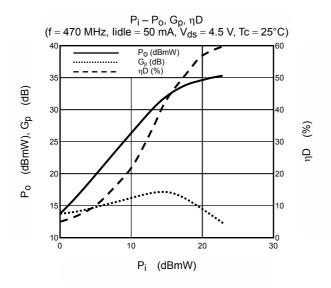
Test Circuit

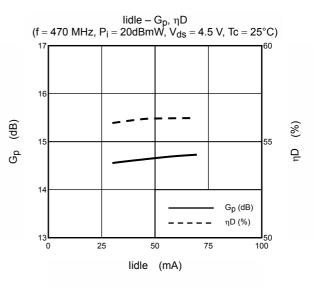


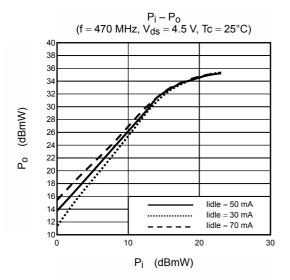
L1: ϕ 0.6 mm enamel wire, 5.8ID, 8T L2: ϕ 0.6 mm enamel wire, 5.8ID, 8T

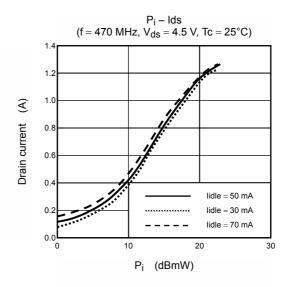
Line: 2mm

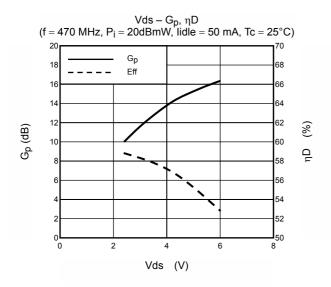
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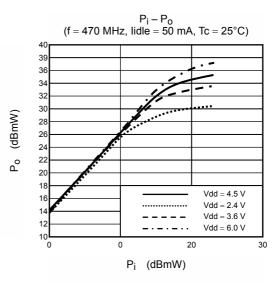




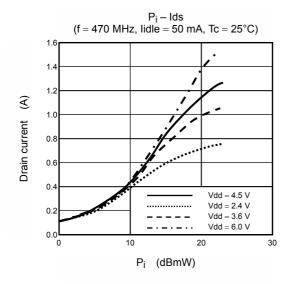








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Caution: These are typical curves and devices are not necessarily guaranteed at these curves.

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